Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

End Application:

Cv-3993/sys-2 e/i fscm 21877

Features Provided:

Programmed and ultraviolet erasable and electrostatic sensitive

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Product Name:

32k x 8-bit prom

Voltage Rating And Type Per Characteristic:

4.5 volts applied and 5.5 volts applied

Time Rating Per Chacteristic:

70.00 nanoseconds access

Memory Device Type:

Prom

Hybrid Technology Type:

Monolithic

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0